TOSHIBA GaAs Linear Integrated Circuit GaAs Monolithic

TG2210FT

RF SPDT Switch

Switch the receive filter for mobile communication. Switch the diversity antenna. Switch the local signal.

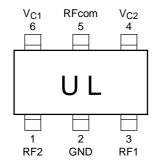
Features

- Low insertion Loss: Loss = 0.4dB (typ.)
- High isolation: ISL = 30dB (typ.)
- Low voltage operation: $V_C = 0 \text{ V}/2.5 \text{ V}$
- Small package: TU6 package $(2.0 \times 1.25 \times 0.6 \text{ mm})$

SSOP6-P-0.65

Weight: 0.008 g (typ.)

Pin Connection, Marking (top view)



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Control voltage	V _{C1}	5	V
Control voltage	V _{C2}	5	V
Input power	Pi	1	W
Operating temperature range	T _{opr}	-40~85	°C
Storage temperature range	T _{stg}	-55~125	°C

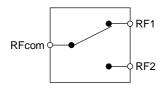
Caution

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

Electrical Characteristics (f = 1 GHz, Ta = 25°C, Zg = ZI = 50 Ω)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Insertion L _{OSS}	L _{OSS} (1)	1	$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V},$ $P_i = 0 \text{dBmW}$	_	0.4	0.7	dB
	L _{OSS} (2)	1	$V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V},$ $P_i = 0 \text{dBmW}$	_	0.4	0.7	dB
Isolation	ISL (1)	1	$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V},$ $P_i = 0 \text{dBmW}$	27	30	_	dB
	ISL (2)	1	$V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V},$ $P_i = 0 \text{dBmW}$	27	30	_	dB
Input power at 1dB gain compression	P _{i1dB}		$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V or } V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V}$	18	_	_	dBmW
Control current	I _{C1}	_	V _{C1} = 0 V, V _{C2} = 3 V or	_	_	0.01	mA
	I _{C2}	_	$V_{C1} = 3 \text{ V}, V_{C2} = 0 \text{ V}$		_	0.01	mA
Switching time	t _{sw}	_	$V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V or } V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V}$	_	200	_	ns

Block Diagram

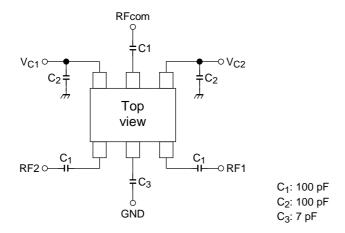


Switch Condition

Control Voltage	Switch Condition
$V_{C1} = 2.5 \text{ V}$	RFcom — RF1 OFF
$V_{C2} = 0 \text{ V}$	RFcom — RF2 ON
V _{C1} = 0 V	RFcom — RF1 ON
V _{C2} = 2.5 V	RFcom — RF2 OFF

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Test Circuit 1 (RF Test Circuit)



Please fix the value of each capacity for using frequency and circuit.

Recommend Capacity

	1 GHz	1.6 GHz	2.4 GHz
C ₁	100 pF	100 pF	100 pF
C ₂	100 pF	100 pF	100 pF
C ₃	7 pF	3 pF	1.5 pF

Notice

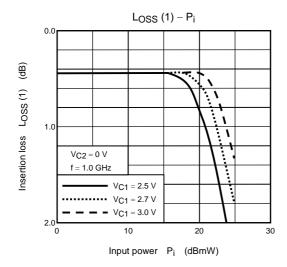
The circuits and measurements contained in this document are given only in the context of as examples of applications for these products.

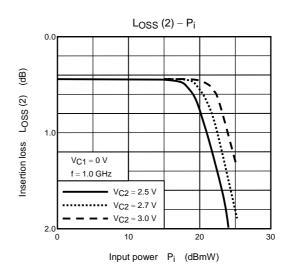
Moreover, these example application circuits are not intended for mass production, since the high-frequency characteristics (the AC characteristics) of these devices will be affected by the external components which the customer uses, by the design of the circuit and by various other conditions.

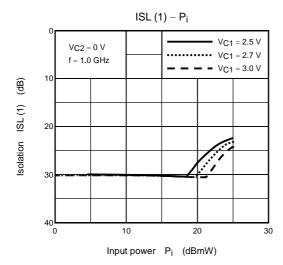
It is the responsibility of the customer to design external circuits which correctly implement the intended application, and to check the characteristics of the design.

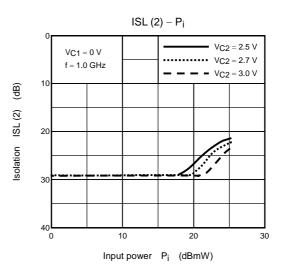
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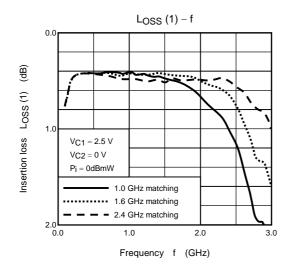
TOSHIBA assume no responsibility for the integrity of customer circuit designs or applications.

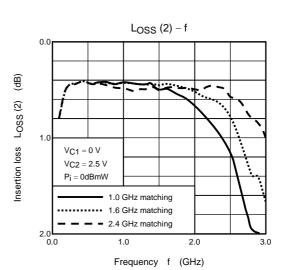


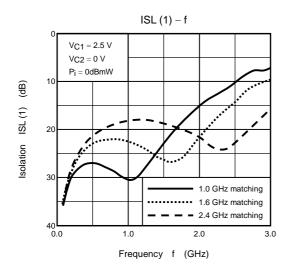


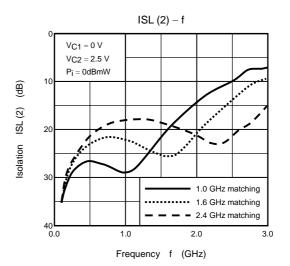


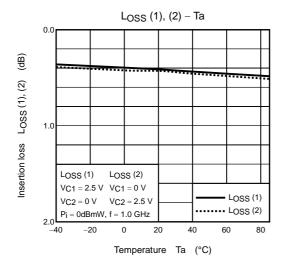


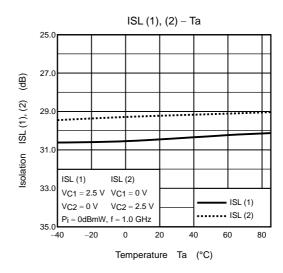


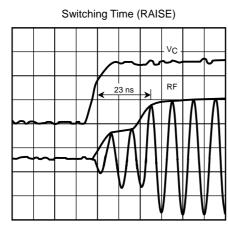


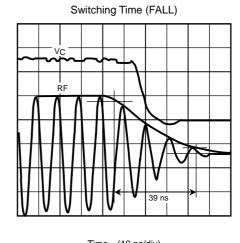










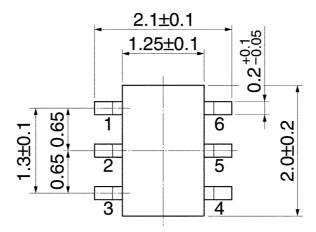


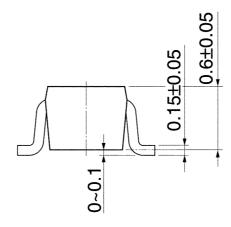
Time (10 ns/div)

Time (10 ns/div)

Package Dimensions

SSOP6-P-0.65 Unit: mm





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Weight: 0.008 g (typ.)

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RESTRICTIONS ON PRODUCT USE

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